Predicted Very Large Thermoelectric Effect in Ferromagnet-Superconductor Junctions in the Presence of a Spin-Splitting Magnetic Field

A. Ozaeta, P. Virtanen, F. S. Bergeret, and T. T. Heikkilä

1Centro de Física de Materiales (CFM-MPC), Centro Mixto CSIC-UPV/EHU, Manuel de Lardizabal 5, E-20018 San Sebastián, Spain
2Low Temperature Laboratory, Aalto University, P.O. Box 15100, FI-00076 Aalto, Finland
3Donostia International Physics Center (DIPC), Manuel de Lardizabal 5, E-20018 San Sebastián, Spain
4Institut für Physik, Carl von Ossietzky Universität, D-26111 Oldenburg, Germany
5Nanoscience Center, Department of Physics, P.O. Box 35 (YFL), FI-40014 University of Jyväskylä, Jyväskylä, Finland

(Received 17 July 2013; published 6 February 2014)

We show that a huge thermoelectric effect can be observed by contacting a superconductor whose density of states is split by a Zeeman field with a ferromagnet with a nonzero polarization. The resulting thermopower exceeds \( k_B/e \) by a large factor, and the thermoelectric figure of merit \( ZT \) can far exceed unity, leading to heat engine efficiencies close to the Carnot limit. We also show that spin-polarized currents can be generated in the superconductor by applying a temperature bias.

Thermoelectric effects, electric potentials generated by temperature gradients and vice versa, are intensely studied because of their possible use in converting the waste heat from various processes to useful energy. The conversion efficiency \( \eta = W/Q \), the ratio of output power \( W \) to the rate of thermal energy consumed \( Q \), in thermoelectric devices however, typically falls short of the theoretical Carnot limit and is low compared to other heat engines, which has motivated an extensive search for better materials. [1]

In electronic conductors a major contributor to thermoelectricity is breaking of the symmetry between positive and negative-energy charge carriers (electrons and holes, respectively) [2]. Within Sommerfeld expansion, this is described by the Mott relation [3], which predicts thermoelectric effects of the order \( \sim k_B T/E_0 \), where \( T \) is the temperature and \( E_0 \), a microscopic energy scale describing the energy dependence in the transport. This is usually a large atomic energy scale (in metals, the Fermi energy), so that \( E_0 \gg k_B T \) even at room temperature and these effects are often weak. Larger electron-hole asymmetries are, however, attainable in semiconductors, as the chemical potential can be tuned close to the band edges, where the density of states varies rapidly [1,4].

The situation in superconductors is superficially similar to semiconductors. The quasiparticle transport is naturally strongly energy dependent due to the presence of the energy gap \( \Delta \), which can be significantly smaller than atomic energy scales. However, the chemical potential is not tunable in the same sense as in semiconductors, as charge neutrality dictates that electron-hole symmetry around the chemical potential is preserved. This implies that the thermoelectric effects in superconductors are often even weaker than in the corresponding normal state, in addition to being masked by supercurrents [5,6].

We show in this Letter that this problem can be overcome in a conventional superconductor by applying a spin-splitting field \( h \). It shifts the energies of electrons with parallel and antiparallel spin orientations to opposite directions [7]. This breaks the electron-hole symmetry for each spin separately, but conserves charge neutrality, as the total density of states remains electron-hole symmetric. In this situation, thermoelectric effects can be obtained by coupling the superconductor to a spin-polarized system. The same type of a mechanism was found to be present in proximity coupled multiterminal superconductor-ferromagnet devices within the model of spin-active interfaces [8].

We propose that this effect can be realized in structures such as shown schematically in Fig. 1: There, a ferromagnet with a relatively large spin polarization is connected to a thin-film superconductor via a tunnel contact. Moreover, we assume the presence of a finite exchange field \( h \) inside the superconductor. Such an exchange field can result from a Zeeman effect due to an applied magnetic field [Fig. 1(b)] [7,9], or from a magnetic proximity effect with either a ferromagnetic insulator [10–13] or with a thin ferromagnetic metallic layer [14,15] placed directly below the superconductor [Fig. 1(a)]. For simplicity, we assume this exchange field to be collinear with the magnetization inside the ferromagnet.

A standard tunneling Hamiltonian calculation [16] yields for spin-\( \sigma \) electrons from the ferromagnet the charge and heat currents

\[
\begin{align*}
I_{\sigma} &= \frac{G_{\sigma}}{e} \int_{-\infty}^{\infty} dEN_{\sigma}(E)[f_F(E) - f_S(E)], \\
Q_{\sigma} &= \frac{G_{\sigma}}{e^2} \int_{-\infty}^{\infty} dE \left( E - \mu_F \right) N_{\sigma}(E) \left[ f_F(E) - f_S(E) \right].
\end{align*}
\]
Here \( N_{1/\downarrow}(E) = N_S(E \pm h) \) is the tunneling density of states (DOS) for spin \( \uparrow / \downarrow \) particles divided by the normal-state density of states at Fermi energy, \[7\] \( N_S(E) = |E|/\sqrt{E^2 - \Delta^2} \delta(|E| - \Delta) \) is the BCS DOS, \( G_\sigma \) is the conductance through the junction for spin \( \sigma \) particles in the normal state, and \( f_{F/S}(E) \) are the (Fermi) distribution functions of electrons inside the ferromagnet and the superconductor, respectively. We disregard the energy dependence of the density of states inside the ferromagnet as well as the tiny electron-hole asymmetry possibly existing in the superconductor. Moreover, we fix the electrochemical potential of the superconductor to zero and describe the applied voltage via the potential \( \mu_F = -eV \) in the ferromagnet. Note that supercurrent cannot flow into the ferromagnet, which prevents it from short-circuiting this potential difference.

The spin-dependent densities of states \( N_\sigma(E) \) are plotted in Fig. 1(c) in the presence of a nonzero exchange field. We can see that they break the symmetry with respect to positive and negative energies for each spin. This symmetry breaking allows for the creation of a large spin-resolved thermoelectric effect, which can be converted to a spin-averaged effect via the spin filtering provided by the polarization \( P \equiv (G_\uparrow - G_\downarrow)/(G_\uparrow + G_\downarrow) \). This can be seen better by introducing the charge and spin currents \( I = I_\uparrow + I_\downarrow \) and \( I_S = I_\uparrow - I_\downarrow \) as well as the heat and spin heat currents \( \dot{Q} = \dot{Q}_\uparrow + \dot{Q}_\downarrow \) and \( \dot{Q}_S = \dot{Q}_\uparrow - \dot{Q}_\downarrow \) along with \( N_0 \equiv (N_\uparrow + N_\downarrow)/2, N_z \equiv N_\uparrow - N_\downarrow \),

\[
I = \frac{G_T}{e} \int_{-\infty}^{\infty} dE \left[ N_0 + \frac{PN_\downarrow}{2} \right] [f_F - f_S],
\]

\[
I_S = \frac{G_T}{e} \int_{-\infty}^{\infty} dE \left[ PN_0 + \frac{N_\downarrow}{2} \right] [f_F - f_S],
\]

\[
\dot{Q} = \frac{G_T}{e^2} \int_{-\infty}^{\infty} dE (E - \mu_F) \left[ N_0 + \frac{PN_\downarrow}{2} \right] [f_F - f_S],
\]

\[
\dot{Q}_S = \frac{G_T}{e^2} \int_{-\infty}^{\infty} dE (E - \mu_F) \left[ PN_0 + \frac{N_\downarrow}{2} \right] [f_F - f_S].
\]

Here \( G_T = G_\uparrow + G_\downarrow \) is the conductance of the tunnel junction that would be measured in the absence of superconductivity. The average density of states \( N_0(E) \) is symmetric and the difference \( N_z(E) \) antisymmetric with respect to \( E = 0 \) as shown in Fig. 1(c). This means that they will pick up a different symmetry component of the distribution function difference in Eqs. (2) and eventually lead to a thermoelectric effect. In order to grasp the size of the thermoelectric effects we assume either a small voltage \( V \) or a small temperature difference \( \Delta T/T = 2(T_L - T_R)/(T_L + T_R) \) across the junctions and find the currents in Eqs. (2) up to linear order in \( V \) and \( \Delta T/T \). They can be written in a compact way, for the charge and heat currents

\[
\begin{pmatrix} I \\ \dot{Q} \end{pmatrix} = \begin{pmatrix} G & P \alpha \\ P \alpha & G_{th}T \end{pmatrix} \begin{pmatrix} V \\ \Delta T/T \end{pmatrix},
\]

and for the spin and spin heat currents

\[
\begin{pmatrix} I_S \\ \dot{Q}_S \end{pmatrix} = \begin{pmatrix} P \Gamma & \alpha \\ \alpha & P \Gamma_{th}T \end{pmatrix} \begin{pmatrix} V \\ \Delta T/T \end{pmatrix}. \]

These response matrices are expressed in terms of three coefficients,

\[
G = G_T \int_{-\infty}^{\infty} dE \frac{1}{4k_0T\cosh^2((E/2k_0T))},
\]

\[
G_{th} = G_T \int_{-\infty}^{\infty} dE \frac{E^2N_0(E)}{4k_0T^2\cosh^2((E/2k_0T))},
\]

\[
\alpha = \frac{G_T}{2e} \int_{-\infty}^{\infty} dE \frac{EN_0(E)}{4k_0T\cosh^3((E/2k_0T))}.
\]

Besides the thermoelectric effect that is detailed below, we can already draw some important conclusions based on Eqs. (3)–(5). (i) The matrices in Eqs. (3)–(4) obey the
Onsager reciprocal relations [8,17,18], which for a generic thermoelectric response matrix \( L \) describing response in a magnetic field \( \vec{B} \) for magnetization \( \vec{m} \) reads
\[
L(\vec{B}, \vec{m}) = L'(\vec{B}, -\vec{m}).
\]
Moreover, the coefficients satisfy a thermodynamic stability condition \( \alpha^2/(TGG_{th}) \leq 1 \), due to Cauchy-Schwartz inequality. (ii) The thermoelectric effects vanish when \( N_z = 0 \), i.e., when either no exchange field is applied \((h = 0)\) or when \( \Delta = 0 \). Since \( N_z(-h) = -N_z(h) \), inverting the exchange field changes the sign of the thermoelectric coefficients. It is important to emphasize that in order to get a nonzero spin-averaged thermoelectric effect, the spin polarization \( P \) of the interface needs to be nonvanishing. (iii) According to Eq. (4), a finite spin-polarized current can flow if there is a temperature difference across the junction. This effect is the longitudinal analog to the spin-Seebeck effect observed in metallic magnets [19,20], and can here be found in a spin-splitting field even for a zero spin polarization \( P = 0 \).

The response coefficients from Eqs. (5) are plotted as a function of exchange field \( h \) in Fig. 2. We note that the thermoelectric coefficient \( \alpha \) increases linearly for small \( h \), and reaches a maximum for \( h < \Delta_0 \) (here, \( \Delta_0 \) is the superconducting order parameter at \( T = 0 \) and \( h = 0 \)), and finally drops to zero when superconductivity is destroyed by \( h \). Thermal conductance \( G_{th} \) has a similar nonmonotonic behavior, whereas the conductance \( G \) increases monotonically toward its normal-state value \( G_T \). In the low temperature limit \( k_BT \ll \Delta - |h| \), the coefficients can be approximated by
\[
G \approx G_T \sqrt{2\pi \Delta} \cosh(h)e^{-\Delta}, \quad (6a)
\]
and
\[
\alpha \approx \frac{G_T}{e} \sqrt{\frac{2\pi}{\Delta}} e^{-\Delta} \left[ \Delta \sinh(h) - h \cosh(h) \right]. \quad (6c)
\]
where \( \Delta = \Delta/(k_BT) \) and \( h = h/(k_BT) \). For \( h = 0 \), the expressions reduce to the standard results for the normal metal-insulator-superconductor (NIS) charge and heat conductance \( G \) and \( G_{th} \), [21,22] whereas \( \alpha \) vanishes.

Instead of the thermally induced current, the typical thermoelectric observable is the thermopower or the Seebeck coefficient \( S = -P\alpha/(GT) \), defined as the voltage \( V \) observed due to a temperature difference \( \Delta T \) after opening the circuit such that \( I = 0 \). It can be obtained from Eqs. (5). The Seebeck coefficient for our ferromagnet-insulator-superconductor (FIS) junction is plotted in the lower right panel of Fig. 2. The qualitative behavior is close to that of \( \alpha \), but it is quantitatively changed by the \( h \) dependence of \( G \).

In the low temperature limit, \( S \) can be obtained from Eqs. (6),
\[
S \approx -(P\Delta/eT)|\tanh(h) - h/\Delta|.
\]
Thus, for low temperatures the thermopower is maximized for \( h = k_BT\arccosh(\sqrt{\Delta}) \), where
\[
S_{\text{max}} \approx -\frac{k_B}{e} \frac{\Delta}{k_BT} \arcsinh\left( \frac{\sqrt{\Delta}}{k_BT} \right).
\]

It can hence greatly exceed \( k_B/e \) and seems to diverge towards low temperatures as \( 1/T \). In practice this divergence is cut off by additional contributions beyond the standard BCS tunnel formula. These are often described via the phenomenological “broadening” parameter \( \Gamma \) [23]. Practical reasons for the occurrence of an effectively nonzero \( \Gamma \) are the fluctuations in the electromagnetic environment [24], the presence of Andreev reflection [25,26], or the inverse proximity effect from the ferromagnet [27,28]. The main effect of the broadening parameter for the thermopower is to induce a finite density of states inside the gap that in turn leads to a correction of the charge conductance (6) of the order \( \delta G = (\Gamma/\Delta)G_T \) (valid for \( \Gamma \ll k_BT \Delta \)). The corrections for the other coefficients are less relevant. Within this limit we get, for the thermopower,
\[
S = \frac{\Delta}{eT} \frac{h \cosh\left( \frac{h}{k_BT} \right) - \Delta \sinh\left( \frac{h}{k_BT} \right)}{\Gamma e^{\Delta/(k_BT)} \sqrt{\frac{k_BT}{2\Delta}} + \Delta \cosh(\frac{h}{k_BT})}.
\]

The result for \( S \) is shown in the lower right panel of Fig. 2.

The power conversion ability of thermoelectric devices is usually characterized by a dimensionless figure of merit \( ZT \), which can here be related to the junction parameters by \( ZT = S^2GT/G_{th} \) where \( G_{th} \) is the thermal conductance at zero current [29]. At linear response, \( \Delta T \ll T \), this determines the efficiency at maximum output power, \( \eta = \eta_{CA}ZT/(ZT + 2) \), where \( \eta_{CA} = 1 - \sqrt{T_{\text{cold}}/T_{\text{hot}}} \) is the Curzon-Ahlborn efficiency [30]. The best known

FIG. 2 (color online). Thermoelectric coefficients vs exchange field \( h \) at \( k_BT/\Delta_0 = 0.1 \) (black lines), 0.2 (blue lines) and 0.3 (red lines). From top left to bottom right: conductance, heat conductance, thermoelectric coefficient, and thermopower. The solid lines are numerical integrals of Eqs. (5), the dashed lines are the approximations in Eqs. (6),(8). The curves have been calculated for \( \Gamma = 10^{-3}\Delta_0 \). \( \Delta_0 \) is the superconducting order parameter at \( T = 0 \) and \( h = 0 \).
thermoelectric bulk materials have $ZT \lesssim 2$, but better efficiencies are achievable in nanostructures [1].

Assuming that the thermal conductance is dominated by the electronic contribution, we find at $k_B T \ll \Delta - |h|$

$$ZT = \frac{P^2}{1 - P^2 + \frac{\Delta^2}{h \cosh(\frac{\Delta}{k_B T}) - \Delta \sinh(\frac{\Delta}{h})}}, \quad (9)$$

which is shown and compared to numerical results in Fig. 3. For $k_B T \ll h$, we find $ZT = P^2/(1 - P^2)$. For $P \to 1$ (half-metal injector), $ZT$ approaches infinity, and the efficiency approaches theoretical upper bounds. From a practical point of view the main challenge in achieving the efficiency approaches theoretical upper bounds. From a practical point of view the main challenge in achieving higher efficiencies is the fabrication of barriers with large spin-polarization $P$.

Let us characterize the efficiency at larger temperature differences. Figure 4 shows the maximum extractable power as a function of the temperature difference, together with the conversion efficiency $\eta$. For a 1 kΩ tunnel junction to aluminum, the maximum power in this figure corresponds to $W \approx 1.5$ pW. The efficiency can be rather high, $\eta \approx 0.7$, also when the extracted power is large.

Other known mechanisms in superconductors generating thermoelectric signals in addition to the normal-state mechanisms include condensate flow [31] and electron-hole symmetry breaking by magnetic impurities [32]. Thermopower significantly larger than the normal-state effect appears also in hybrid N/S systems. [33]

The cooling effect found in NIS junctions in the non-linear regime [34,35] is also similar to the effect described here, if one substitutes the exchange field with a finite voltage $V \approx \Delta/e$. Indeed, the extracted power found above is comparable to the maximum cooling power of a NIS junction. NIS junctions, however, cannot be used for power conversion, as their cooling power $Q_{NIS}$ is a symmetric function of the bias voltage. The effect of ferromagnetism on NIS cooling was also discussed earlier, [36–38] but in those works the exchange field was introduced in order to suppress the Joule heating due to the Andreev current and did not affect the density of the states of the superconductor. According to our results, the induced exchange field in the superconductor may lead to a larger cooling efficiency than in NIS junctions.

The assumption about equilibrium electron distributions in the above model holds if the resistance $G_T^{-1}$ is large compared to the quasiparticle boundary resistance $R_q \sim \rho_N \epsilon_{in}/A$, [39] which depends on the inelastic charge and spin relaxation length $\epsilon_{in}$ (A is the junction area and $\rho_N$ the normal-state resistivity). In the opposite limit, the kinetics of injection and relaxation of quasiparticles in the superconductor (and the ferromagnet) need to be modeled [40,41] taking the split density of states into account, which can alter the quantitative details.

We also note that in the geometry of Fig. 1(b), where the Zeeman field is induced by a magnetic field, the orbital effect of the magnetic field will also influence the form of the density of states and for large fields it will eventually lead to a destruction of superconductivity. For simplicity, we have disregarded this effect in the above calculation. In practice, to minimize this effect, the magnetic field should be applied preferably in the longitudinal direction of the wire [42], as depicted in Fig. 1(b).

Summarizing, we have shown that a junction between a conventional superconductor in the presence of an exchange field and a ferromagnet with polarization $P$ exhibits huge thermoelectric effects. The thermopower diverges at low temperatures in the absence of limiting effects, yielding a figure of merit $ZT \approx P^2/(1 - P^2)$ and heat engine efficiencies close to theoretical upper bounds. Moreover, even in the case of $P = 0$ our model predicts $\eta = 0.4$ for $ZT = 4.04$ and the Carnot efficiencies $\eta_C = 1 - T_{cold}/T_{hot}$ are also shown (dotted lines).
finite spin currents in the presence of a temperature gradient, provided there is a spin-splitting of the density of states. These mechanisms in principle can work also in semiconductors without requiring doping which typically deteriorates the thermoelectric effects.

The authors thank V. Golovach for useful discussions. The work of F. S. B and A. O. has been supported by the Spanish Ministry of Economy and Competitiveness under Project No. FIS2011-28851-C02-02 and the Basque Government under UPV/EHU Project IT-756-13. The work of T. T. H. and P. V. has been supported by the Academy of Finland, the European Research Council (Grant No. 228464). A. O. Fund under JAE-Predoc program and the EU-FP 7 (Grant No. 308850) program. The work of A. O. has also been supported by the CSIC and the European Social.

[29] The thermal conductance at zero current $G_{th}$ is related to $G_{th}$ at zero voltage difference [cf. Eqs. (3)–(4)] by the expression $G_{th} = G_{th} - (Pe)^2/GT$; see Littman and B. Davidson, J. Appl. Phys. 32, 217 (1961).